



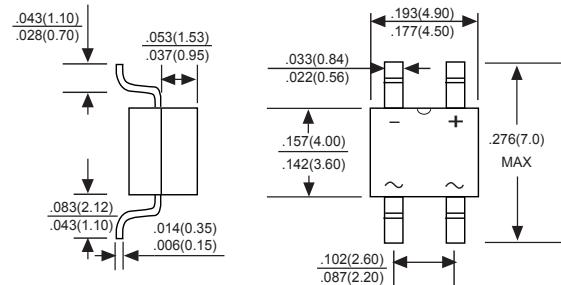
UMB1S THRU UMB10S

Voltage Range - 100 to 1000 V olts Current - 1.0 Ampere

GLASS PASSIVATED ULTRA FAST RECOVERY BRIDGE RECTIFIERS

Features

- ◆ Glass Passivated Chip Junction
- ◆ Reverse Voltage - 100 to 1000 V
- ◆ Forward Current - 1.0 A
- ◆ Fast reverse recovery time
- ◆ Designed for Surface Mount Application



Mechanical Data

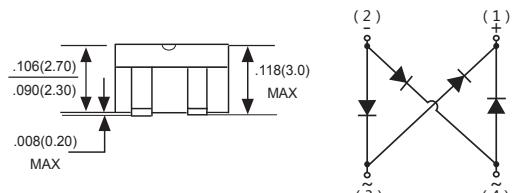
Case : JEDEC MBS Molded plastic body

Terminals : Solder plated, solderable per MIL-STD-750, Method 2026

Polarity : Polarity symbol marking on body

Mounting Position : Any

Weight : 0.0035 ounce, 0.1 grams



Dimensions in inches and (millimeters)

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter	SYMBOLS	MDD UMB1S	MDD UMB2S	MDD UMB4S	MDD UMB6S	MDD UMB8S	MDD UMB10S	UNITS
Marking Code								
Maximum repetitive peak reverse voltage	V_{RRM}	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	100	200	400	600	800	1000	V
Average Rectified Output Current at $T_c = 125^\circ C$	$I_{F(AV)}$				1.0			A
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}				35			A
Maximum instantaneous forward voltage drop per leg at 1.0A	V_F		1.0	1.3	1.5			V
Maximum DC reverse current at rated DC blocking voltage	I_R			5 100				uA
Typical Junction Capacitance (NOTE 1)	C_J			18				pF
Maximum reverse recovery time (NOTE 3)	t_{rr}		50		75			ns
Typical thermal resistance(NOTE 2)	$R_{\theta JA}$ $R_{\theta JC}$			80 30				°C/W
Operating temperature range	T_J			-55 to +150				°C
storage temperature range	T_{STG}			-55 to +150				°C

NOTES:1.Measured at 1MHz and applied reverse voltage of 4 V D.C..

2.Mounted on glass epoxy PC board with 4x1.5" x 1.5" (3.81x3.81 cm) copper pad.

3.Reverse recovery condition IF=0.5A,IR=1.0A,Irr=0.25A.

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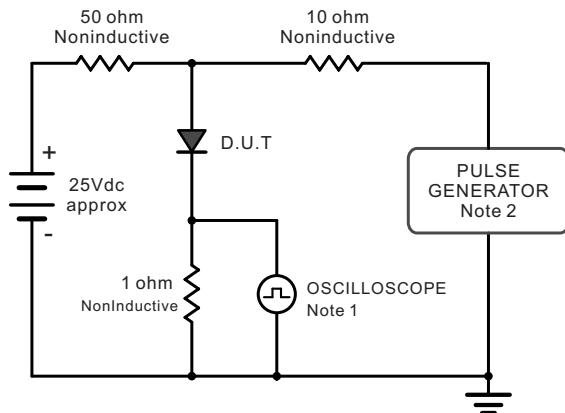


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Ratings And Characteristic Curves

Fig.1 Reverse Recovery Time Characteristic And Test Circuit Diagram



Note: 1. Rise Time = 7ns, max.
Input Impedance = 1megohm,22pF.
2. Fall Time = 10ns, max.
Source Impedance = 50 ohms.

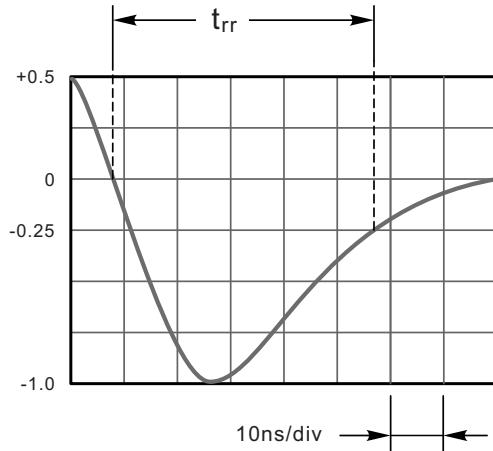


Fig.2 Maximum Average Forward Current Rating

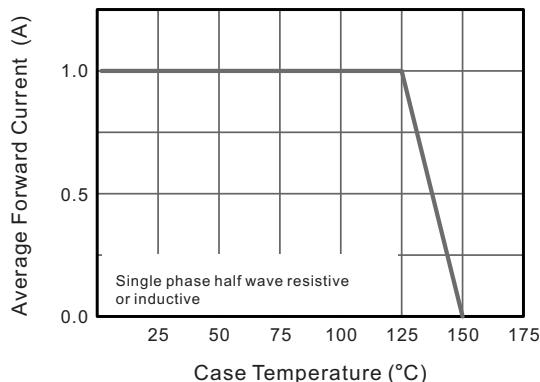


Fig.3 Typical Reverse Characteristics

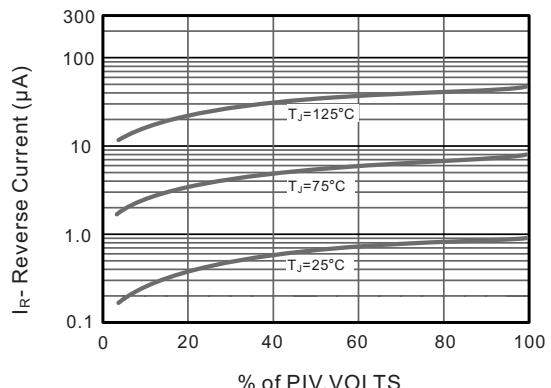


Fig.3 Typical Instantaneous Forward Characteristics

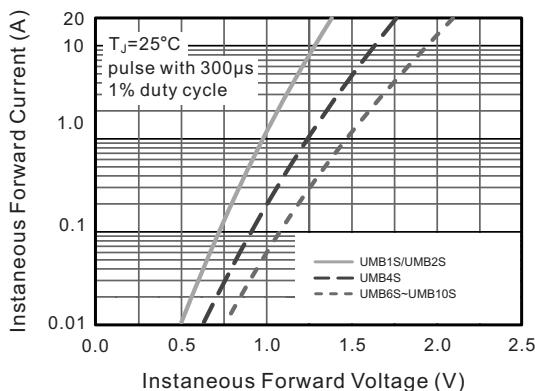
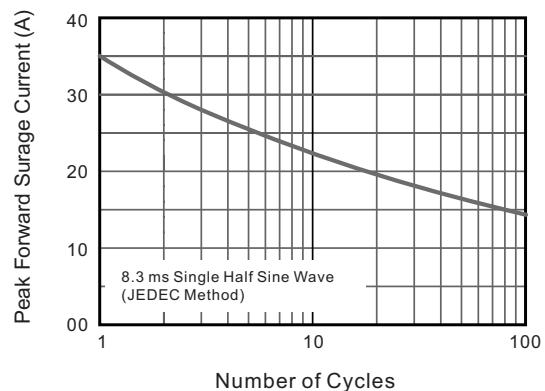
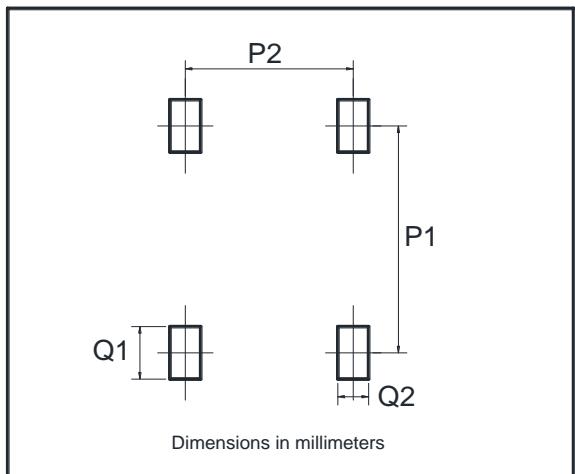


Fig.4 Maximum Non-Repetitive Peak Forward Surge Current



The curve above is for reference only.

Suggested Pad Layout



Dim	Min
P1	6.00
P2	2.40
Q1	1.84
Q2	1.20